

Ordering number : EN5951

CMOS IC



LC75757E, 75757W

1/3 Duty VFD Driver with Key Input Function



Overview

The LC75757E and LC75757W are 1/3 duty VFD drivers that can be used for electronic tuning frequency display and other applications under the control of a micro-controller. These products can directly drive VFDs with up to 123 segments. It also includes a key scan circuit and can support input from up to 25 keys and can thus reduce the number of lines to the front panel in application systems.

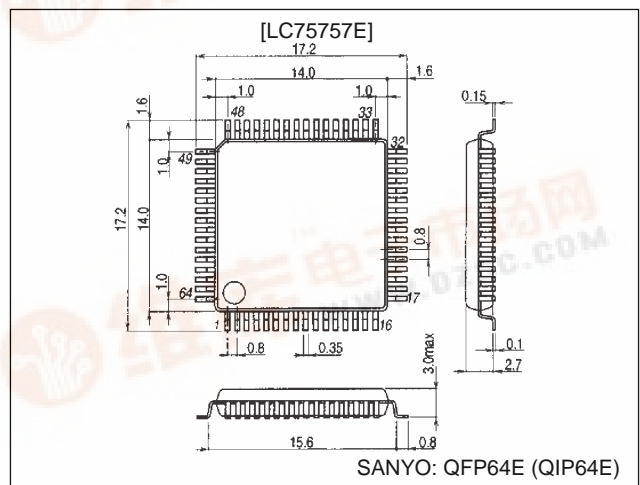
Features

- Key input from up to 25 keys
(Key scans are only performed when keys are pressed.)
- 123 segment outputs.
- Noise reduction circuits are built into the output drivers.
- Serial data I/O supports CCB format communication with the system controller.
- Dimmer and sleep mode can be controlled by serial data input.
- High generality since display data is displayed without the intervention of a decoder.
- All segments can be turned off with the $\overline{\text{BLK}}$ pin.

Package Dimensions

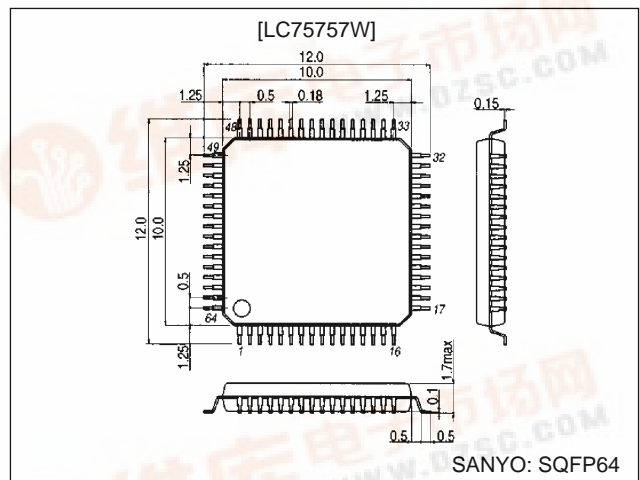
unit: mm

3151-QFP64E



unit: mm

3190-SQFP64



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• CCB is SANYO's original bus format and all the bus addresses are controlled by SANYO.

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Specifications

Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$, $V_{SS} = 0\text{ V}$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum Supply voltage	$V_{DD\text{ max}}$	V_{DD}	-0.3 to +6.5	V
	$V_{FL\text{ max}}$	V_{FL}	-0.3 to +21.0	V
Input voltage	V_{IN1}	DI, CL, CE, $\overline{\text{BLK}}$	-0.3 to +6.5	V
	V_{IN2}	OSCI, KI1 to KI5	-0.3 to $V_{DD} + 0.3$	V
Output voltage	V_{OUT1}	S1 to S41, G1 to G3	-0.3 to $V_{FL} + 0.3$	V
	V_{OUT2}	OSCO, KS1 to KS5	-0.3 to $V_{DD} + 0.3$	V
	V_{OUT3}	DO	-0.3 to +6.5	V
Output current	I_{OUT1}	S1 to S41	6	mA
	I_{OUT2}	G1 to G3	60	mA
	I_{OUT3}	KS1 to KS5	1	mA
Allowable power dissipation	Pd max	$T_a = 85^\circ\text{C}$ (LC75757E)	400	mW
		$T_a = 85^\circ\text{C}$ (LC75757W)	300	mW
Operating temperature	T_{opr}		-40 to +85	$^\circ\text{C}$
Storage temperature	T_{stg}		-50 to +150	$^\circ\text{C}$

Allowable Operating Ranges at $T_a = -40$ to $+85^\circ\text{C}$, $V_{DD} = 4.5$ to 5.5 V , $V_{SS} = 0\text{ V}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Supply voltage	V_{DD}	V_{DD}	4.5	5.0	5.5	V
	V_{FL}	V_{FL}	8	12	18	V
High-level input voltage	V_{IH1}	DI, CL, CE, $\overline{\text{BLK}}$	$0.8 V_{DD}$		5.5	V
	V_{IH2}	OSCI	$0.8 V_{DD}$		V_{DD}	V
	V_{IH3}	KI1 to KI5	$0.6 V_{DD}$		V_{DD}	V
Low-level input voltage	V_{IL}	DI, CL, CE, $\overline{\text{BLK}}$, OSCI, KI1 to KI5	0		$0.2 V_{DD}$	V
Guaranteed oscillator frequency range	f_{OSC}	OSCI, OSCO	0.9	2.4	3.7	MHz
Recommended external resistor value	R_{OSC}	OSCI, OSCO	2.2	12	47	$\text{k}\Omega$
Recommended external capacitor value	C_{OSC}	OSCI, OSCO	15	33	100	pF
Clock low-level pulse width	$t_{\phi L}$	CL : See figure 1.	160			ns
Clock high-level pulse width	$t_{\phi H}$	CL : See figure 1.	160			ns
Data setup time	t_{ds}	DI, CL : See figure 1.	160			ns
Data hold time	t_{dh}	DI, CL : See figure 1.	160			ns
CE wait time	t_{cp}	CE, CL : See figure 1.	160			ns
CE setup time	t_{cs}	CE, CL : See figure 1.	160			ns
CE hold time	t_{ch}	CE, CL : See figure 1.	160			ns
DO output delay time	t_{dc}	DO: $R_{PU} = 4.7\text{ k}\Omega$, $C_L = 10\text{ pF}^*$: See figure 1.			1.5	μs
DO rise time	t_{dr}	DO: $R_{PU} = 4.7\text{ k}\Omega$, $C_L = 10\text{ pF}^*$: See figure 1.			1.5	μs
$\overline{\text{BLK}}$ switching time	t_c	$\overline{\text{BLK}}$, CE : See figure 4.	10			μs

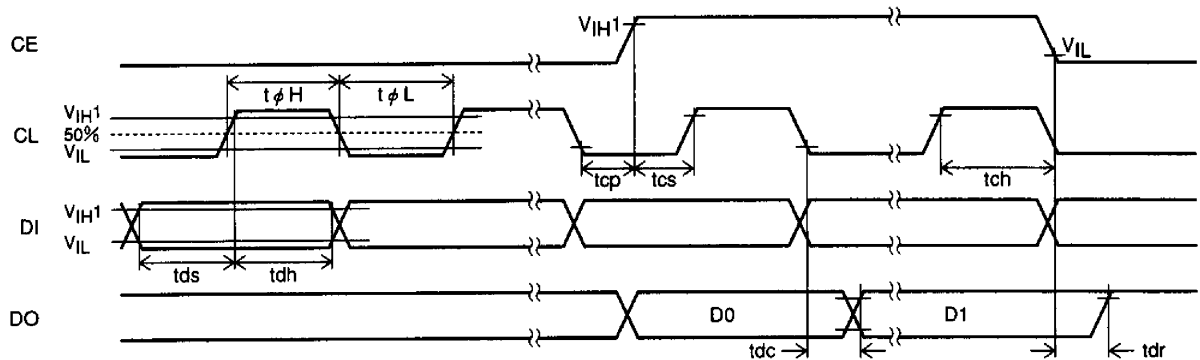
Note: Since DO is an open-drain output, these values will vary with the pull-up resistance R_{PU} and the load capacitance C_L .

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Electrical Characteristics in the Allowable Operating Ranges

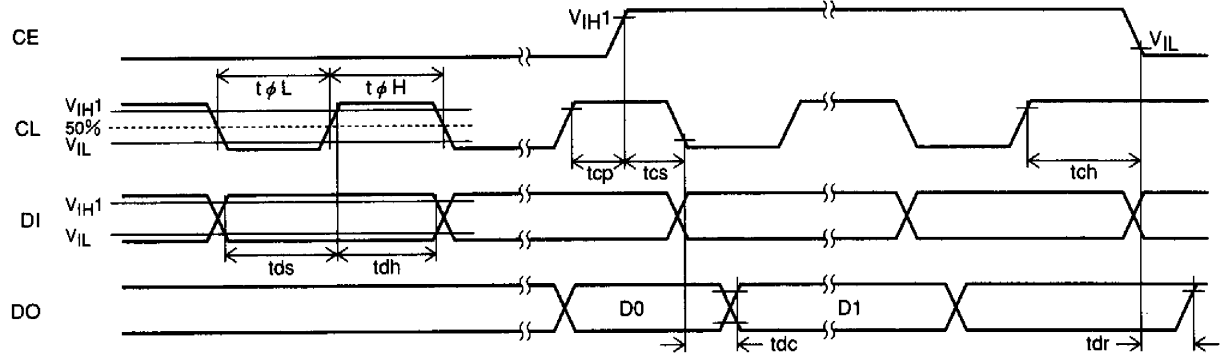
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
High-level input current	I_{IH1}	DI, CL, CE, \overline{BLK} : $V_{IN} = 5.5\text{ V}$			5	μA
	I_{IH2}	OSCI: $V_{IN} = V_{DD}$			5	μA
Low-level input current	I_{IL}	DI, CL, CE, \overline{BLK} , OSCI: $V_{IN} = 0\text{ V}$	-5			μA
Input floating voltage	V_{IF}	KI1 to KI5			$0.05 V_{DD}$	V
Pull-down resistance	R_{PD}	KI1 to KI5: $V_{DD} = 5.0\text{ V}$	50	100	250	$\text{k}\Omega$
Output off leakage current	I_{OFFH}	DO: $V_O = 5.5\text{ V}$			5	μA
High-level output voltage	V_{OH1}	S1 to S41: $I_O = -2\text{ mA}$	$V_{FL} - 0.6$			V
	V_{OH2}	G1 to G3: $I_O = -50\text{ mA}$	$V_{FL} - 1.3$			V
	V_{OH3}	OSCO: $I_O = -0.5\text{ mA}$	$V_{DD} - 2.0$			V
	V_{OH4}	KS1 to KS5: $I_O = -500\text{ }\mu\text{A}$	$V_{DD} - 1.2$	$V_{DD} - 0.5$	$V_{DD} - 0.2$	V
Low-level output voltage	V_{OL1}	S1 to S41, G1 to G3: $I_O = 50\text{ }\mu\text{A}$			0.5	V
	V_{OL2}	OSCO: $I_O = 0.5\text{ mA}$			2.0	V
	V_{OL3}	KS1 to KS5: $I_O = 25\text{ }\mu\text{A}$	0.2	0.5	1.5	V
	V_{OL4}	DO: $I_O = 1\text{ mA}$		0.1	0.5	V
Oscillator frequency	f_{OSC}	$R_{OSC} = 12\text{ k}\Omega$, $C_{OSC} = 33\text{ pF}$		2.4		MHz
Hysteresis voltage	V_H	DI, CL, CE, \overline{BLK} , KI1 to KI5		$0.1 V_{DD}$		V
Current drain	I_{DD1}	Sleep mode			5	μA
	I_{DD2}	Outputs open: $f_{OSC} = 2.4\text{ MHz}$			10	mA

- When stopped with CL at the low level



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- When stopped with CL at the high level

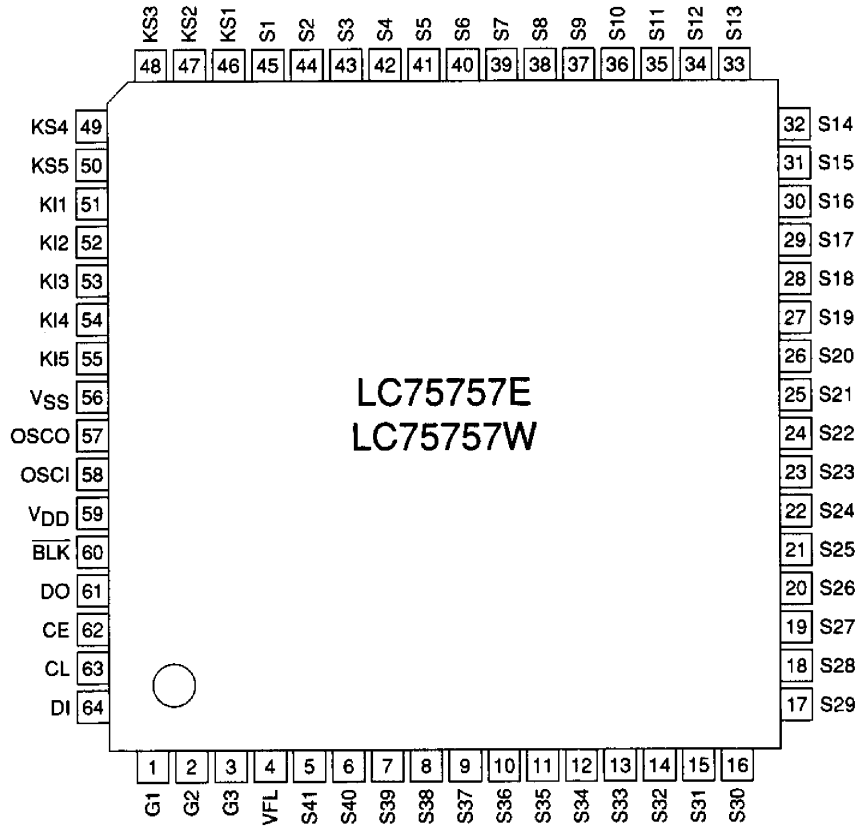


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Figure 1

LC75757E, LC75757W

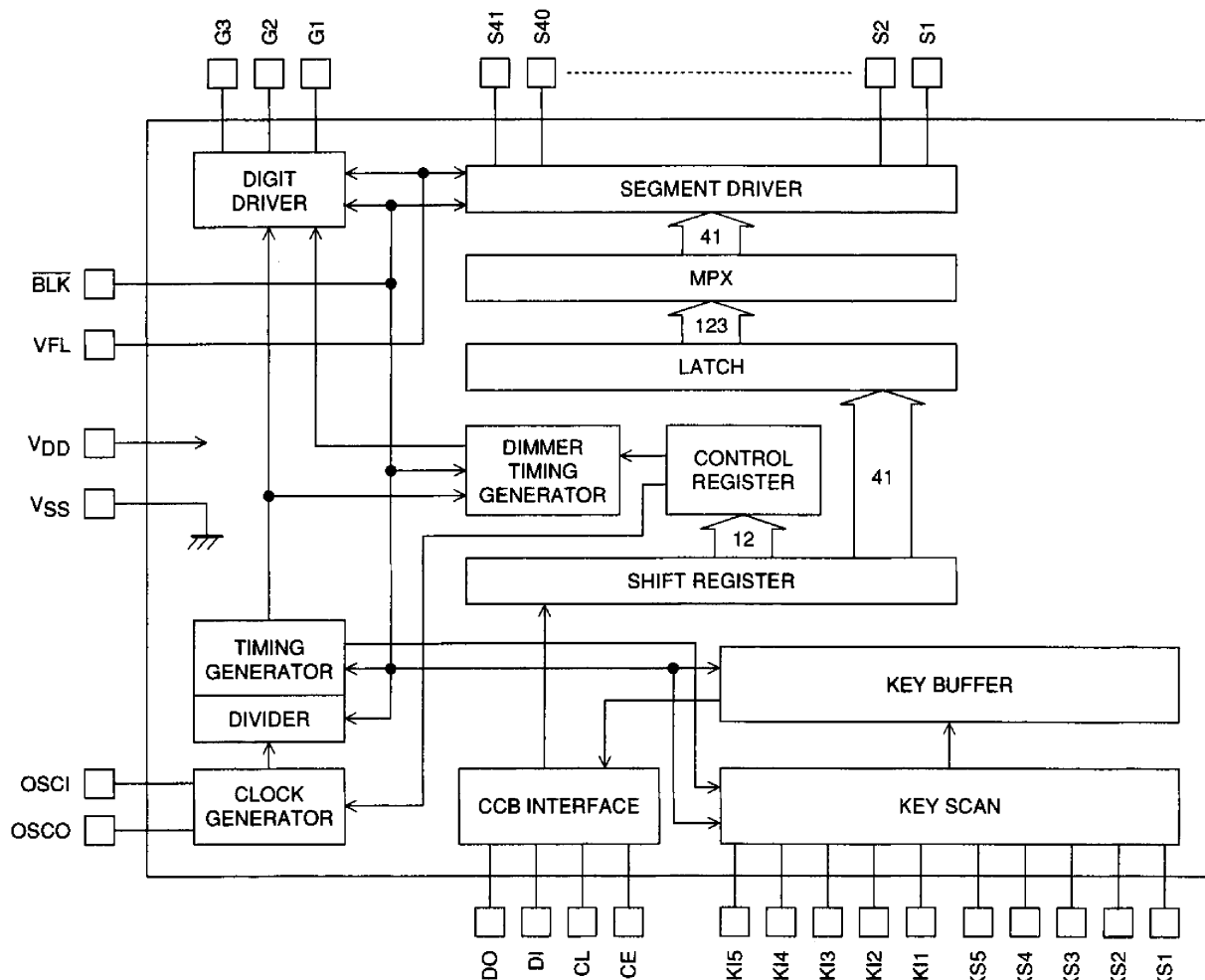
Pin Assignment



A11018
Top view

LC75757E, LC75757W

Block Diagram



A11019

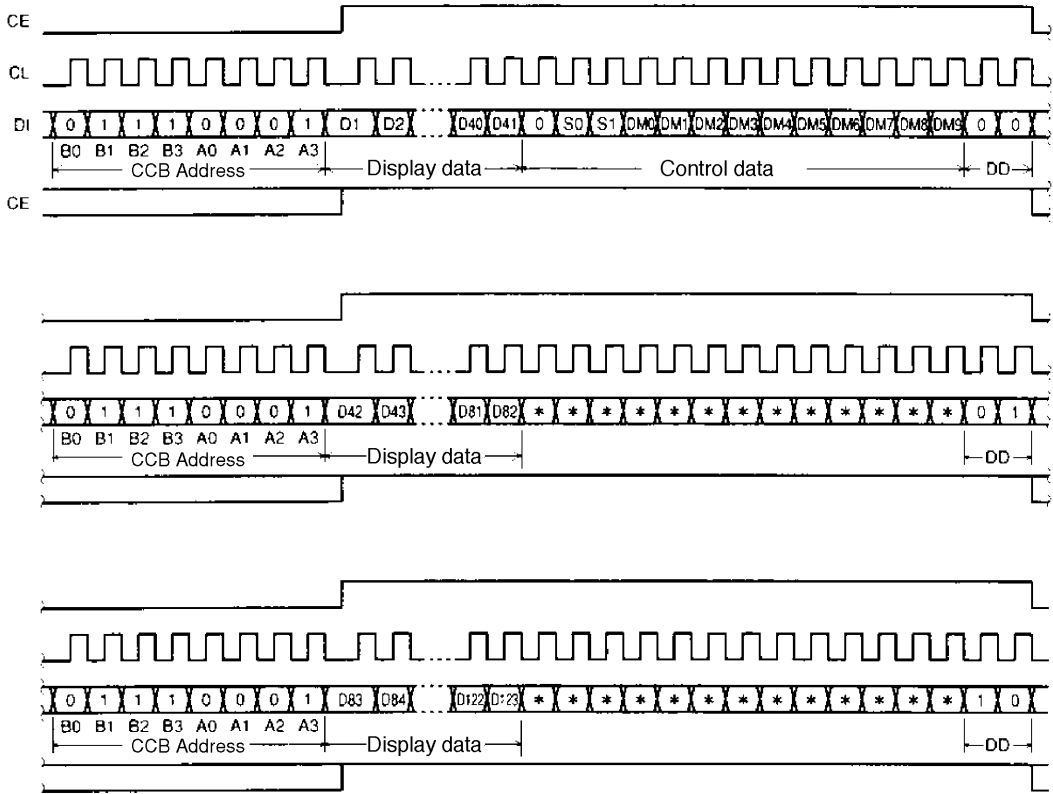
Pin Descriptions

Pin No.	Pin	Function	I/O	Handling when unused
4	V _{FL}	Driver block power supply. Applications must provide a voltage in the range 8.0 to 18.0 V.	—	—
59	V _{DD}	Logic block power supply. Applications must provide a voltage in the range 4.5 to 5.5 V.	—	—
56	V _{SS}	Power supply ground. This pin must be connected to the system ground.	—	—
58	OSC1	Oscillator circuit connections. An oscillator circuit is formed by connecting a resistor and a capacitor externally to these pins.	I	GND
57	OSCO		O	OPEN
60	BLK	Reset signal input used to initialize the IC internal state. During a reset, the display is turned off forcibly regardless of the internal display data. Also note that the internal key data is all reset to 0 and key scan operations are disabled. However, serial data input is possible in this state.	I	GND
63	CL	Serial data interface. These pins must be connected to the system microcontroller. Note that since DO is an open-drain output, a pull-up resistor is required. CL: Synchronization clock DI: Transfer data CE: Chip enable DO: Output data	I	GND
64	DI			
62	CE			
61	DO			
1 to 3	G1 to G3	Digit outputs. The frame frequency f_D is $(f_{OSC}/6144)$ Hz.	O	OPEN
45 to 5	S1 to S41	Segment outputs that display the display data transferred over the serial interface.	O	OPEN
46 to 50	KS1 to KS5	Key scan outputs. Normally, when a key matrix is formed, diodes are inserted in the key scan timing lines to prevent shorts. However, since this IC uses unbalanced CMOS outputs in the output transistor circuit, the IC will not be damaged if these outputs are shorted.	O	OPEN
51 to 55	K11 to K15	Key scan inputs. Pull-down resistors are built into the IC internal pin circuits.	I	GND

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Serial Data Input

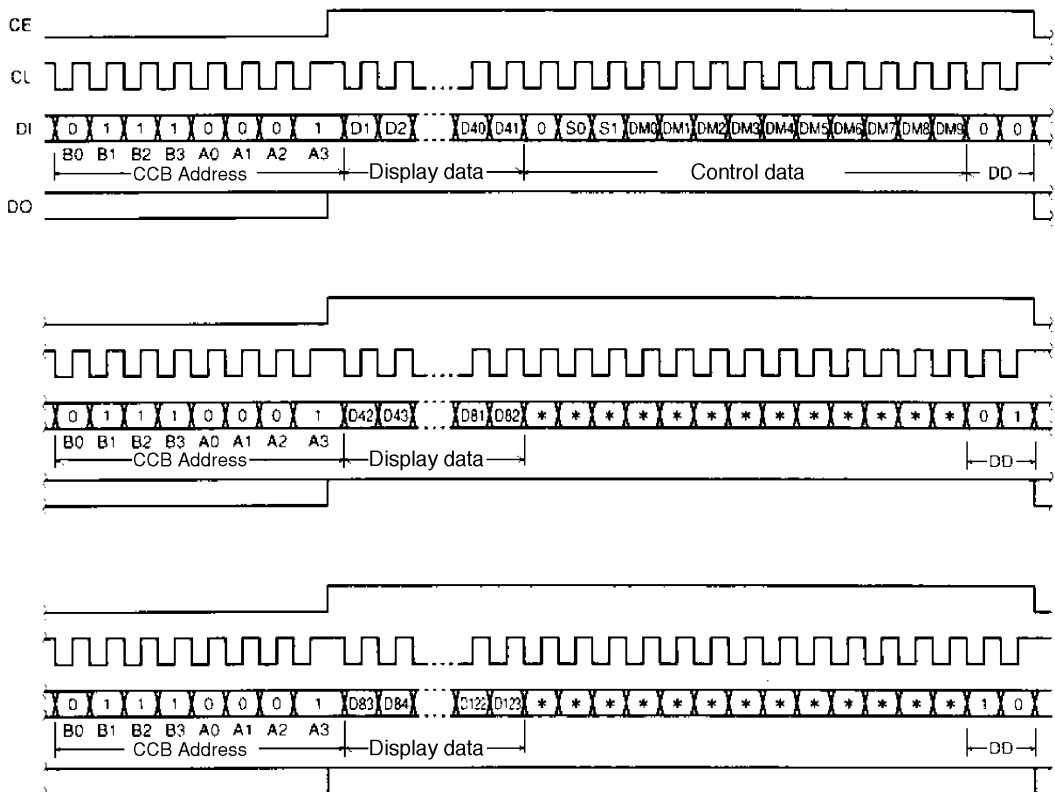
- When stopped with CL at the low level



Note: don't care
DD: Direction data

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- When stopped with CL at the high level



Note: don't care
DD: Direction data

Figure 2

LC75757E, LC75757W

- CCB address: Applications must send the value 01110001_B (8E_H) as shown in figure 2.
- D1 to D41: Segment display data for the G1 digit output pin
 Dn (n = 1 to 41) = 1: Segment on
 Dn (n = 1 to 41) = 0: Segment off
- D42 to D82: Segment display data for the G2 digit output pin
 Dn (n = 42 to 82) = 1: Segment on
 Dn (n = 42 to 82) = 0: Segment off
- D83 to D123: Segment display data for the G3 digit output pin
 Dn (n = 83 to 123) = 1: Segment on
 Dn (n = 83 to 123) = 0: Segment off
- S0, S1: Sleep control data
- DM0 to DM9: Dimmer data

Control Data

- S0, S1: Sleep control data

This control data controls switching between sleep mode and normal mode, and also sets the states of the KS1 to KS5 key scan output pins in key scan standby mode.

Control data		Mode	Clock generator (oscillator circuit)	Segment outputs Digit output	Output pin states during key scan standby				
S0	S1				KS1	KS2	KS3	KS4	KS5
0	0	Normal	Oscillator operating	Operating	H	H	H	H	H
0	1	Sleep	Stopped	L	L	L	L	L	H
1	0	Sleep	Stopped	L	L	L	H	H	H
1	1	Sleep	Stopped	L	H	H	H	H	H

- DM0 to DM9: Dimmer data

This data controls the duty of the G1 to G3 digit output pins. This data forms a 10-bit binary value in which D0 is the LSB. The brightness of the display can be controlled by adjusting the duty of the G1 to G3 digit output pins. The table lists the relationship between the dimmer data and the dimmer value.

DM9	DM8	DM7	DM6	DM5	DM4	DM3	DM2	DM1	DM0	Dimmer value (t4/t3)
0	0	0	0	0	0	0	0	0	0	0/1024
0	0	0	0	0	0	0	0	0	1	1/1024
0	0	0	0	0	0	0	0	1	0	2/1024
to										
1	1	1	1	1	1	1	1	0	0	1020/1024
1	1	1	1	1	1	1	1	0	1	1021/1024
1	1	1	1	1	1	1	1	1	0	1022/1024
1	1	1	1	1	1	1	1	1	1	Illegal setting

t3 and t4: See figure 5.

Relationship between the Display Data (D1 to D123) and the Segment Output Pins

Segment output pin	G1	G2	G3	Segment output pin	G1	G2	G3	Segment output pin	G1	G2	G3
S1	D1	D42	D83	S15	D15	D56	D97	S29	D29	D70	D111
S2	D2	D43	D84	S16	D16	D57	D98	S30	D30	D71	D112
S3	D3	D44	D85	S17	D17	D58	D99	S31	D31	D72	D113
S4	D4	D45	D86	S18	D18	D59	D100	S32	D32	D73	D114
S5	D5	D46	D87	S19	D19	D60	D101	S33	D33	D74	D115
S6	D6	D47	D88	S20	D20	D61	D102	S34	D34	D75	D116
S7	D7	D48	D89	S21	D21	D62	D103	S35	D35	D76	D117
S8	D8	D49	D90	S22	D22	D63	D104	S36	D36	D77	D118
S9	D9	D50	D91	S23	D23	D64	D105	S37	D37	D78	D119
S10	D10	D51	D92	S24	D24	D65	D106	S38	D38	D79	D120
S11	D11	D52	D93	S25	D25	D66	D107	S39	D39	D80	D121
S12	D12	D53	D94	S26	D26	D67	D108	S40	D40	D81	D122
S13	D13	D54	D95	S27	D27	D68	D109	S41	D41	D82	D123
S14	D14	D55	D96	S28	D28	D69	D110				

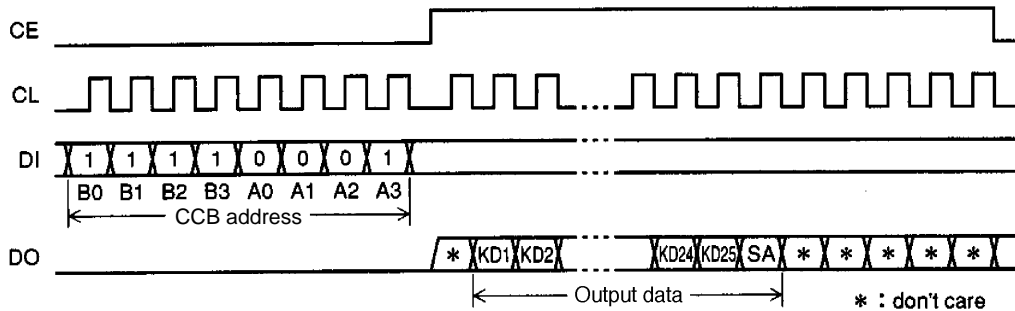
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As an example, the table below lists the operation of the S11 segment output pin.

Display data			Segment output pin (S11) state
D11	D52	D93	
0	0	0	The segments corresponding to the G1 to G3 digit output pins are off
0	0	1	The segment corresponding to the G3 digit output pin is turned on
0	1	0	The segment corresponding to the G2 digit output pin is on
0	1	1	The segments corresponding to the G2 and G3 digit output pins are on
1	0	0	The segment corresponding to the G1 digit output pin is on
1	0	1	The segments corresponding to the G1 and G3 digit output pins are on
1	1	0	The segments corresponding to the G1 and G2 digit output pins are on
1	1	1	The segments corresponding to the G1 to G3 digit output pins are on

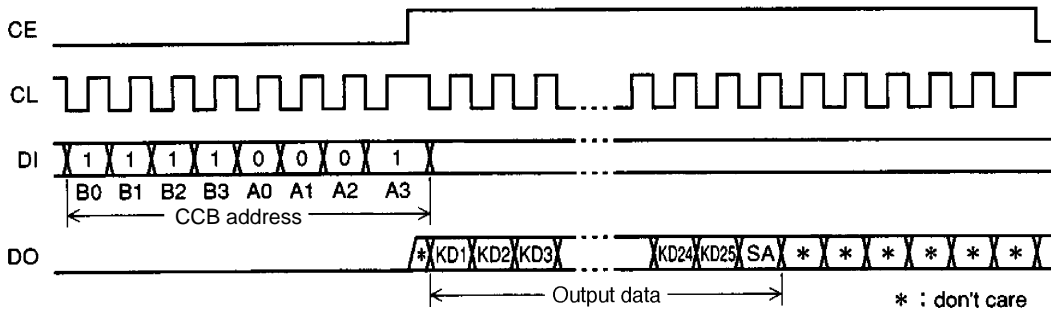
Serial Data Output

- When stopped with CL at the low level



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- When stopped with CL at the high level



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Figure 3

- CCB address: Applications must send the value 11110001_B (8F_H) as shown in figure 3.
- KD1 to KD25: Key data
- SA: Sleep acknowledge data

Note: The key data (KD1 to KD25) and the sleep acknowledge data (SA) will be invalid if the key data is read when DO is high.

Output Data

• KD1 to KD25: Key data

These bits represent the key output states when a key matrix with up to 25 keys is formed using the KS1 to KS5 key scan output pins and the KI1 to KI5 key scan input pins. When a key is pressed, the bit corresponding to that key will be set to 1. The correspondence is listed in the following table.

Item	KI1	KI2	KI3	KI4	KI5
KS1	KD1	KD2	KD3	KD4	KD5
KS2	KD6	KD7	KD8	KD9	KD10
KS3	KD11	KD12	KD13	KD14	KD15
KS4	KD16	KD17	KD18	KD19	KD20
KS5	KD21	KD22	KD23	KD24	KD25

• SA: Sleep acknowledge data

This output data is set to the state when the key was pressed. In that case DO will go to the low level. If serial data is input during this period and the mode is set (normal mode or sleep mode), the IC will be set to that mode. SA is set to 1 in the sleep mode and to 0 in the normal mode.

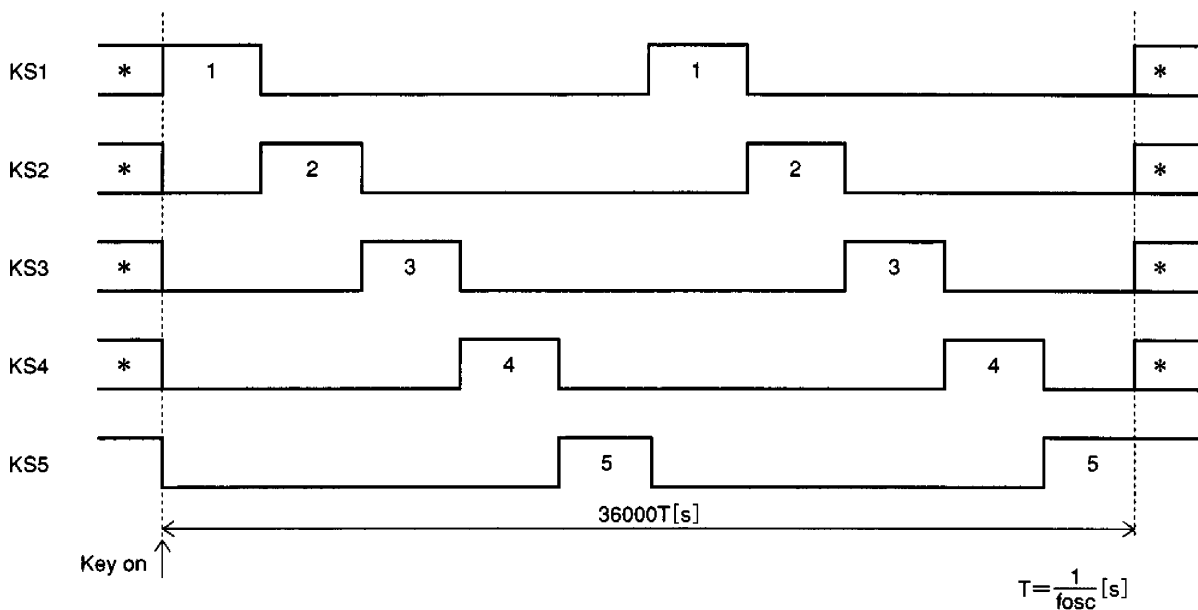
Sleep Mode

The IC is set to sleep mode by setting either S0 or S1 in the control data to 1. The segment outputs and the digit outputs are all set low, and the clock generator (oscillator circuit) is stopped (although it is restarted when a key is pressed), and thus power dissipation is reduced. This mode is cleared by setting S0 and S1 in the control data to 0.

Key Scan Operation

• Key scan timing

The scan period is $18000T$ [s]. A key scan is performed twice to reliably recognize the key on/off states by verifying that the key data for the two scans agrees. If the data agrees, the IC recognizes a key press and $38400T$ [s] after the start of key scan execution issues a key scan data read request by outputting a low level from DO. If the key data does not agree and a key was pressed at the later scan, the IC executes another key scan operation. Note that this means that this IC cannot recognize a key press shorter than $38400T$ [s].

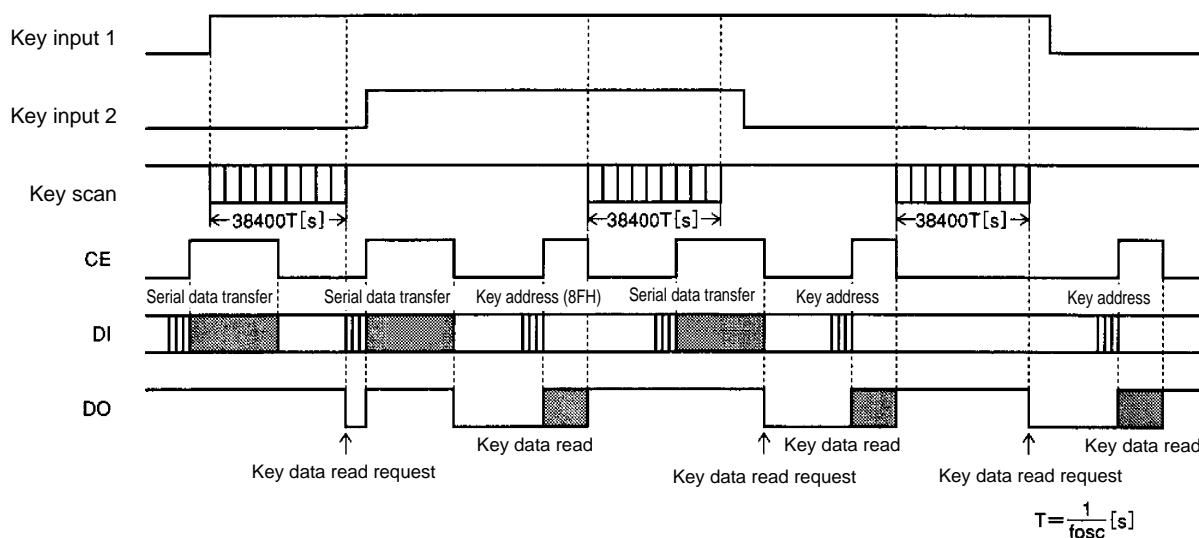


Note *: The high-level and low-level states in sleep mode are set according to the control data S0 and S1. Key scan output signals are not output from pins set to the "L" state.

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- In normal mode

- The pins KS1 to KS5 are set high.
- A key scan is started when any of the keys is pressed, and the keys are kept scanning until all keys are released. The controller can recognize simultaneous multiple key presses by checking the key data for multiple bits being set.
- If a key is pressed for over 38400T [s] (where $T = 1/f_{OSC}$), the IC outputs a key data read request to the controller by setting DO low. The controller acknowledges this state and reads the key data. However, note that DO will go high when CE is set high during the serial data transfer.
- After the controller key data readout completes, the key data read request will be cleared (DO will be set high), and the IC performs another key scan. Note that since DO is an open-drain output, a pull-up resistor (between 1 and 10 k Ω) is required.

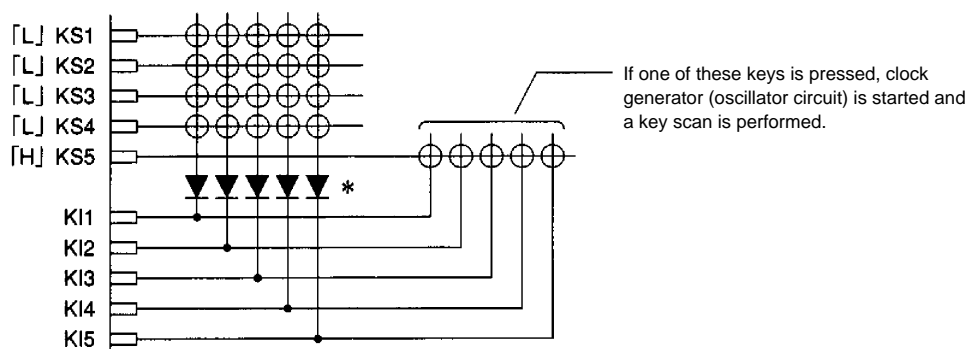


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- In sleep mode

- The pins KS1 to KS5 are set to high or low according to the values of S0 and S1 in the control data. (See the description of the control data elsewhere in this document.)
- If a key connected to one of the KS1 to KS5 lines that was set high is pressed, the clock generator (oscillator circuit) is started and a key scan is performed, and the keys are kept scanning until all keys are released. The controller can recognize simultaneous multiple key presses by checking the key data for multiple bits being set.
- If a key is pressed for over 38400T [s] (where $T = 1/f_{OSC}$), the IC outputs a key data read request to the controller by setting DO low. The controller acknowledges this state and reads the key data. However, note that DO will go high when CE is set high during the serial data transfer.
- After the controller key data readout completes, the key data read request will be cleared (DO will be set high), and the IC performs another key scan. However, sleep mode will not be cleared. Note that since DO is an open-drain output, a pull-up resistor (between 1 and 10 k Ω) is required.
- Example of a key scan operation in sleep mode

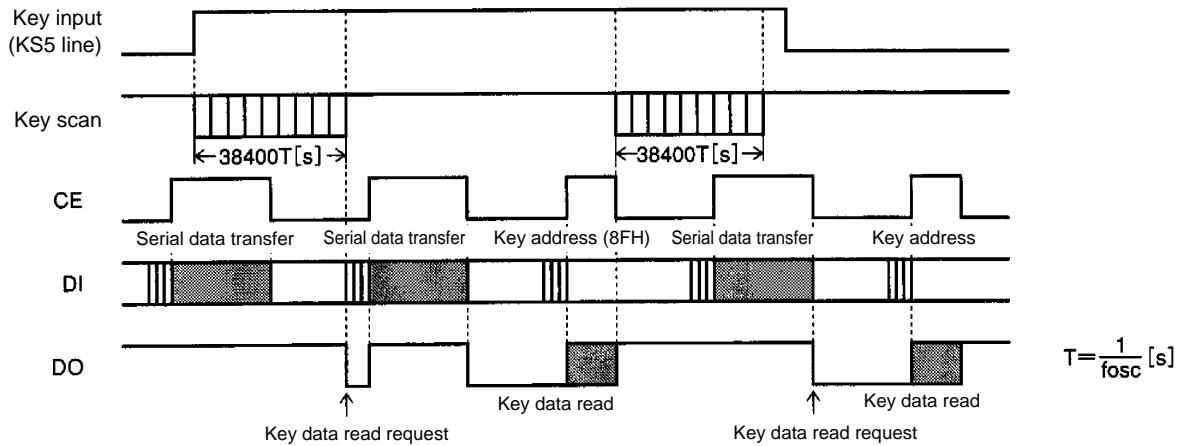
Example: Sleep mode with S1 = 0, S1 = 1 (Only KS5 is set high)



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Note *: These diodes are required to reliably recognize multiple key presses on the KS5 line when the IC is set to sleep mode with only KS5 set to high as in the example above. That is, they prevent incorrect recognition of key presses due to sneak currents arising from simultaneous presses of keys on the KS1 through KS4 lines.

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Multiple Key Presses

The LC75757E/W, even without diodes in the key scan lines, can scan for any combination of dual key presses, any combination of triple key presses on any of the KI1 to KI5 key scan input pin lines, or any combination of multiple key presses on any of the KS1 to KS5 key scan output lines. However, keys that are not pressed may be seen as having been pressed for any other multiple key press combination. Accordingly, applications must insert diodes at each key. Also, to reject any triple and higher multiple key presses, if three or more data readouts are 1 ignore the data by the software or in other ways.

Notes on the \overline{BLK} Pin and Display Control

Since the states of the IC internal data (D1 to D123, and the control data) are undefined when power is first applied, applications should turn off the display (i.e. set S1 to S41, and G1 to G3 low) by setting the \overline{BLK} pin low at the same time as power is applied. Applications should transfer all 192 bits of the serial data while \overline{BLK} is held low, and only then set \overline{BLK} high. This will prevent random meaningless display at power on. (See figure 4.)

Note on the Power on Sequence

Applications must observe the following sequences when turning the power on or off.

- At power on: First turn on the logic system power (V_{DD}), and then turn on the driver power (V_{FL})
- At power off: First turn off the driver power (V_{FL}), and then turn off the logic system power (V_{DD}).

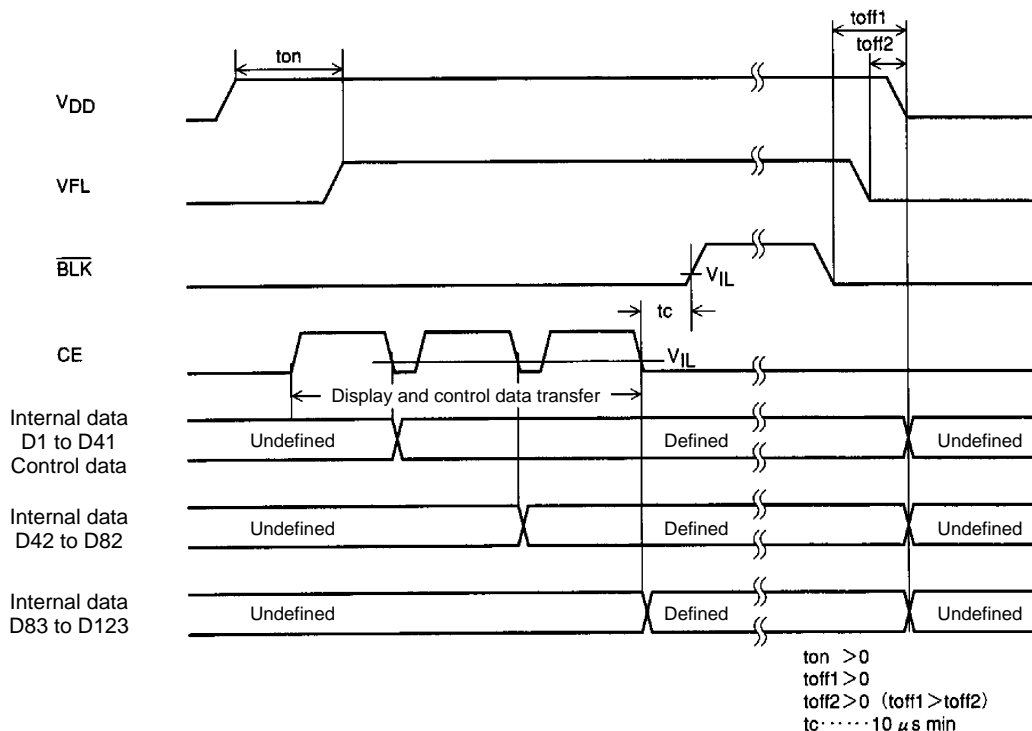
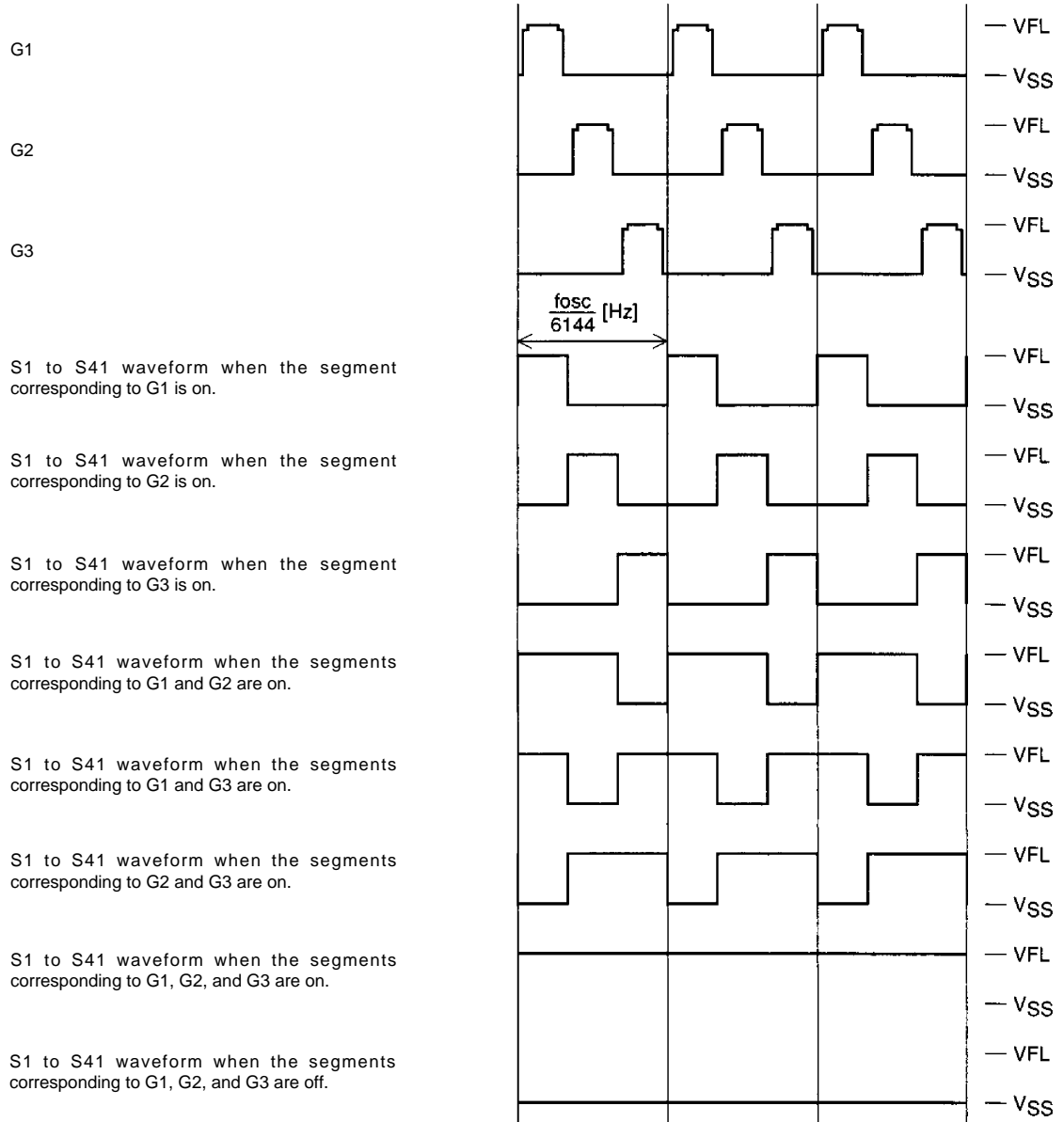


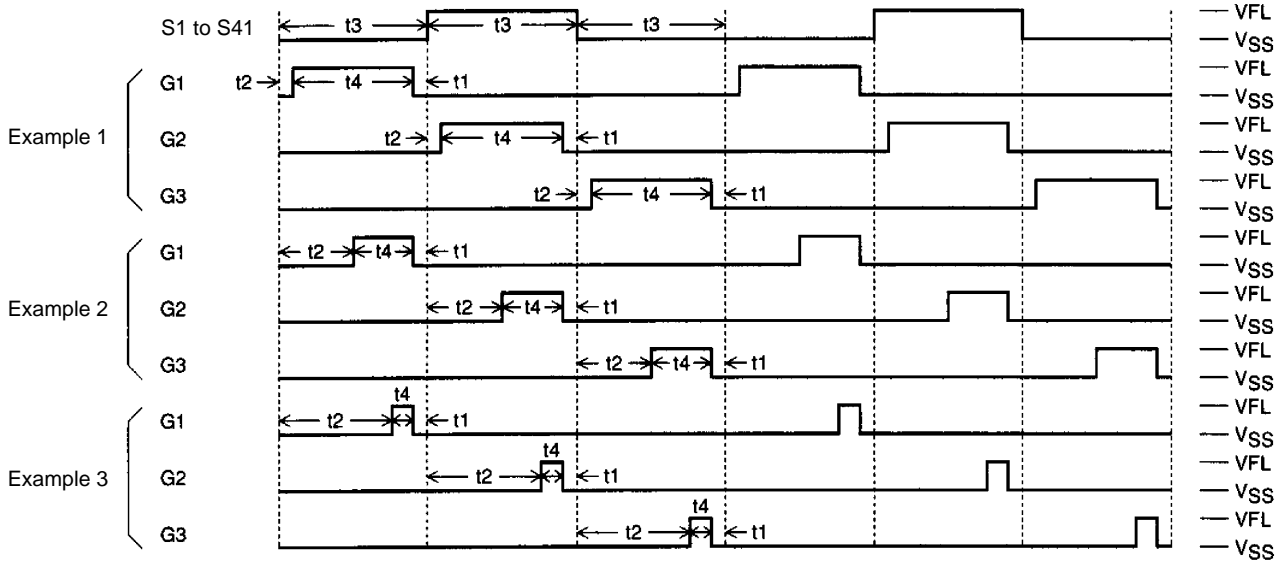
Figure 4

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Output Waveforms (S1 to S41)



Relationship between the Segment and Digit Outputs



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Figure 5

- Figure 5 shows the case where the display data is set up so that the segment outputs S1 to S41 output the V_{SS} level with the same timing as the G1 and G3 digit outputs, and output the V_{FL} level with the same timing as the G2 digit output. Here, the segments corresponding to G2 will be turned on. The relationship between t3 and the oscillator frequency f_{OSC} in this case is t3 = 2048/f_{OSC}.
- The G1 to G3 digit output waveforms in example 1 correspond to a dimmer data (DM0 to DM9) set to 3FE_H. The relationship between t1 and the oscillator frequency f_{OSC} is t1 = 2/f_{OSC}. Note that t1 and t2 in example 1 are identical times.
- The G1 to G3 digit output waveforms in example 2 correspond to a dimmer data (DM0 to DM9) set to a smaller value. Although t1 does not change, t2 becomes longer. Here, if the dimmer data (DM0 to DM9) is set to 1FF_H and the oscillator frequency f_{OSC} is 2.4 MHz, then t2 can be calculated as follows.

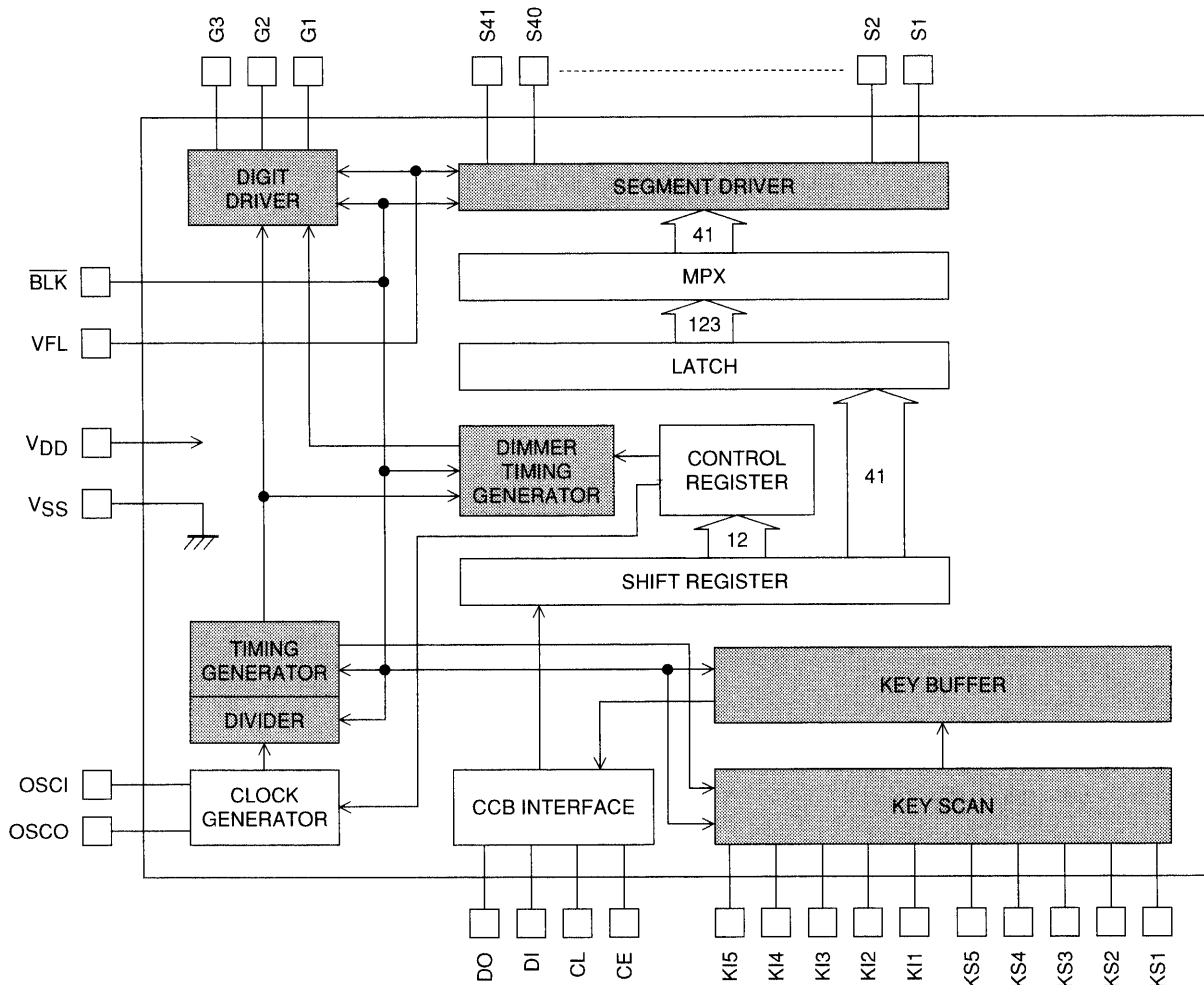
$$\begin{aligned}
 t2 &= t3 - t1 \times (1FF_H + 1) \\
 &= \frac{1024}{f_{OSC}} \\
 &= 0.43 \text{ [ms]}
 \end{aligned}$$

- If the dimmer data (DM0 to DM9) is set to an even smaller value, t2 will become even longer as shown in example 3. Note that t1 does not change in this case as well.

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Block States during the Reset Period (when $\overline{\text{BLK}}$ is low)

- **Divider and timing generator**
These circuits are reset and their base clock is stopped.
- **Dimmer timing generator**
The circuit is reset and its operation is stopped.
- **Digit and segment drivers**
These circuits are reset and the display is turned off (S1 to S41 and G1 to G3 are set low.)
- **Key scan**
The circuit is reset, its internal circuits are set to the initial state, and key scanning is disabled.
- **Key buffer**
The circuit is reset and all data is set to 0.
- **Clock generator**
The state (normal or sleep mode) of this block (the clock oscillator circuit) is determined after the sleep control data (S0 and S1) is transferred.
- **CCB interface, shift register, control register, latch, and multiplexer**
These circuits are not reset so that serial data can be input during the reset period.



: Blocks that are reset.

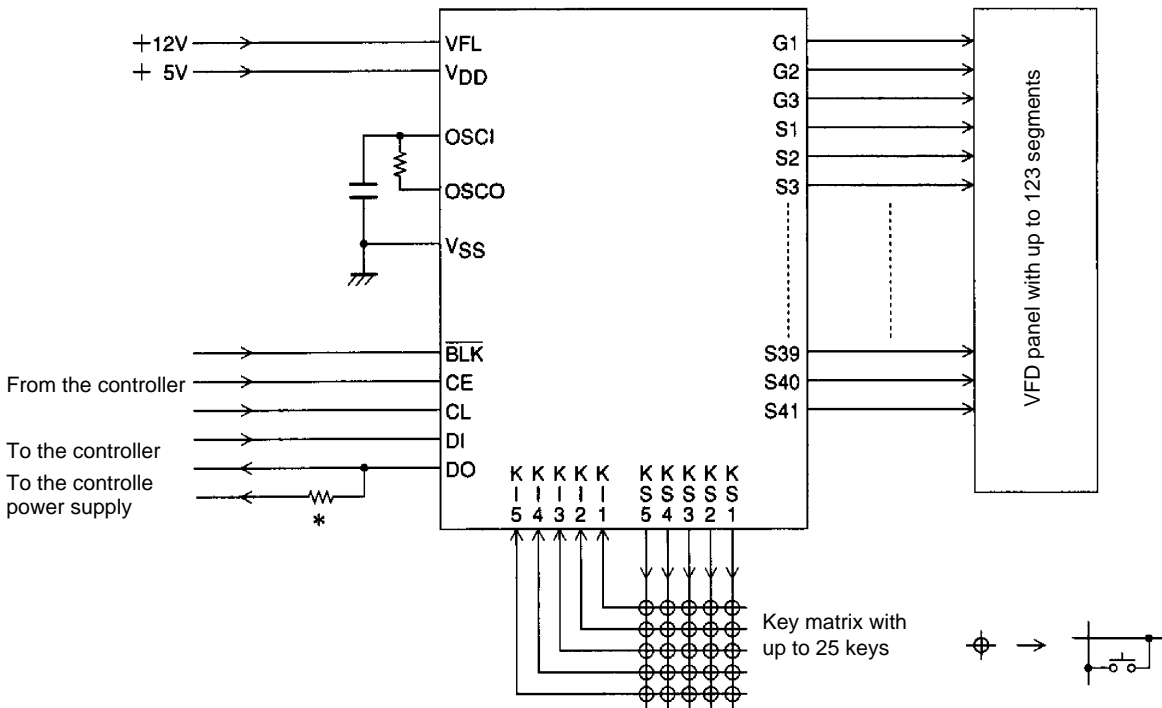
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Output Pin States during the Reset Period (when $\overline{\text{BLK}}$ is low)

Output pin	State during reset
S1 to S4	L
G1 to G3	L
KS1 to KS4	X *1
KS5	H
DO	H *2

- Notes: 1. The state of this pin is undefined after power has been applied until the sleep control data (S0 and S1) are transferred.
 2. Since this pin is an open-drain output, a pull-up resistor (between 1 and 10 k Ω) is required. It remains high during the reset period even if the controller attempts to read the key data.

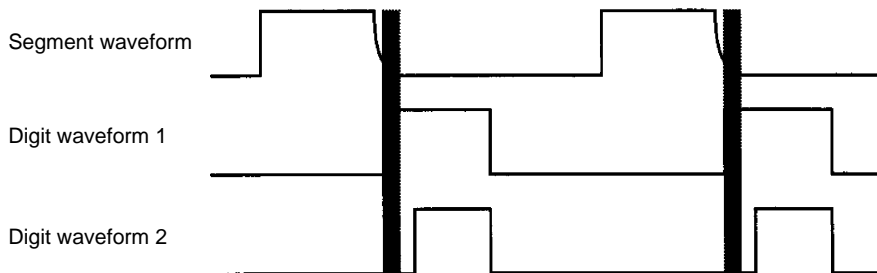
Sample Application Circuit



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Note *: Since DO is an open-drain output, a pull-up resistor is required. Select a value in the range 1 to 10 k Ω that is most appropriate for the capacitance of the external lines so that the waveform is not distorted.

Notes on the Segment and Digit Waveforms



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Figure 6

The segment waveform is somewhat deformed due to the VFD panel itself and the circuit wiring. Furthermore, if a digit waveform such as digit waveform 1 in which no dimming is applied is used, the display will glow dimly. Therefore, applications must take this waveform deformation into account and apply adequate dimming such as that shown in digit waveform 2 so that this phenomenon does not occur.

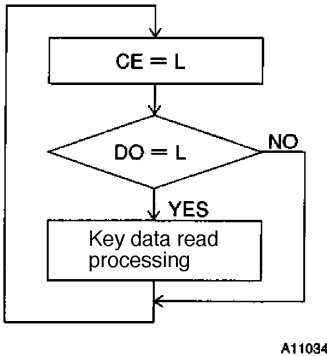
Notes on Controller Transfer of Display Data

Since the display data is transferred in three operations as shown in figure 2, we strongly recommend that applications transfer all the data within a 30 ms period to assure display quality.

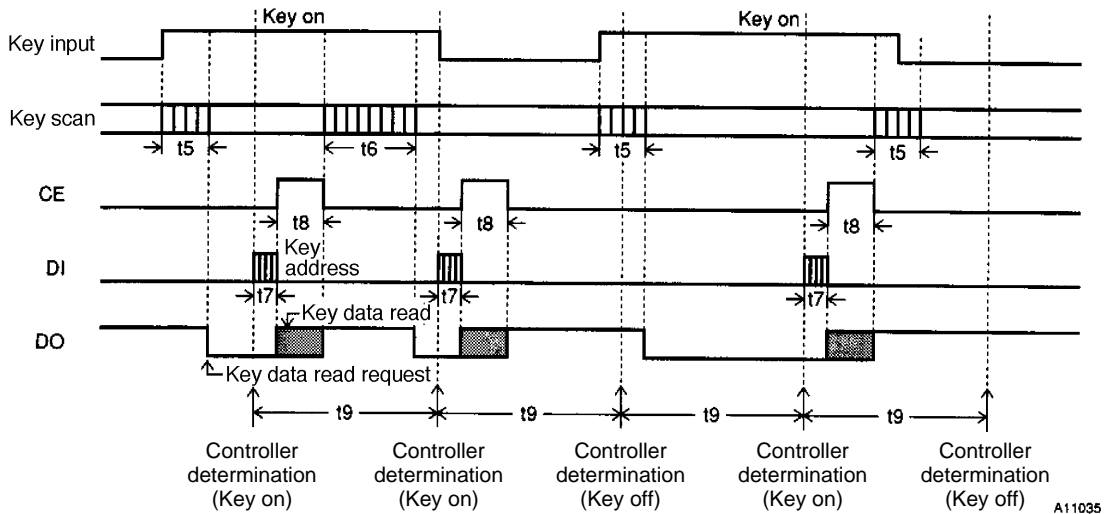
Controller Key Data Readout Procedure

When the controller uses a timer to read out the key data

- Flowchart



- Timing chart



- t5.....Key scan execution time (38400T [s]) when the key data for two key scan operations matches.
 - t6.....Key scan execution time (76800T [s]) when the key data for the first two key scan operations does not match.
 - t7.....Key address (8FH) transfer time
 - t8.....Key data readout time
- $$T = \frac{1}{f_{OSC}} \text{ [s]}$$

- Operation

When the controller use timer processing for key on/off determination and key data readout, it must set CE low and check the state of DO at least once every t9 period. If DO is low, the controller must recognize that a key has been pressed and read out the key data.

The period t9 must obey the following inequality:

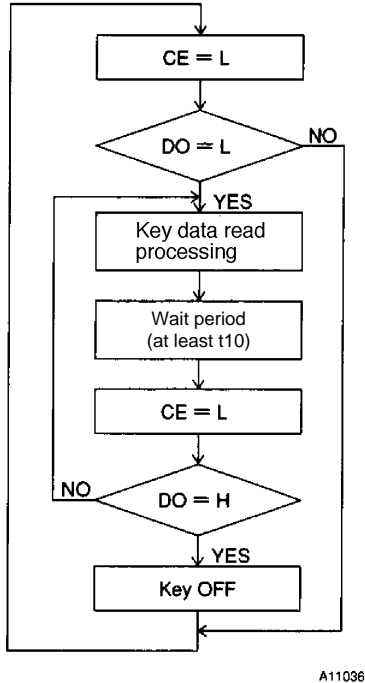
$$t9 > t7 + t8 + t6$$

Note that if the controller reads out key data when DO is high, both the key data (KD1 to KD25) and the sleep acknowledge data will be invalid data.

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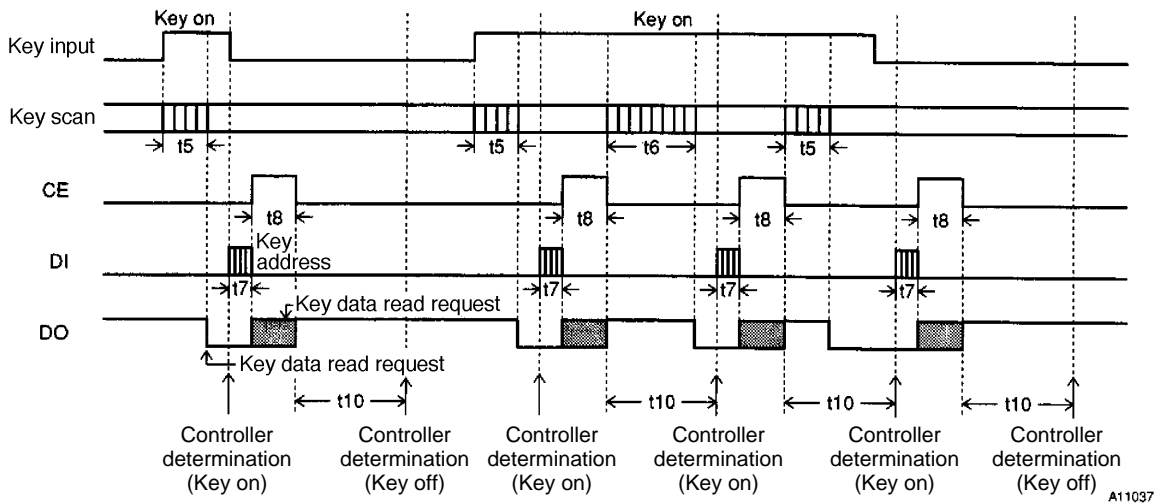
When the controller uses interrupt processing to read out the key data

- Flowchart



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- Timing chart



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t5.....Key scan execution time (38400T [s]) when the key data for two key scan operations matches.

t6.....Key scan execution time (76800T [s]) when the key data for the first two key scan operations does not match.

t7..... Key address (8FH) transfer time $T = \frac{1}{f_{OSC}}$ [s]

t8.....Key data readout time

- Operation

When the controller uses interrupt processing for key on/off determination and key data readout, it must check the state of DO when CE is low, and perform a key data readout if DO is low. The next time the controller checks the on/off states of the keys, it must make that determination at a time t10 after the last readout based on the state of DO when CE is low, and then read out the key data. The time t10 must obey the following inequality:

$$t10 > t6$$

Note that if the controller reads out key data when DO is high, both the key data (KD1 to KD25) and the sleep acknowledge data will be invalid data.

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